UP05C8G

Silicon NPN epitaxial planar type (Tr) Silicon epitaxial planar type (CCD load device)

For CCD output circuits

■ Features

- Two elements incorporated into one package (Tr + CCD load device)
- Costs can be reduced through downsizing of the equipment and reduction of the number of parts.

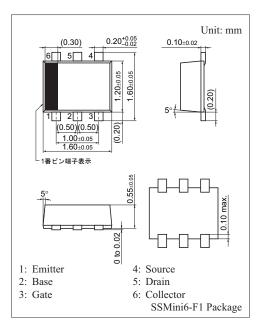
■ Basic Part Number

• 2SC3932 + CCD load device

■ Absolute Maximum Ratings $T_a = 25$ °C

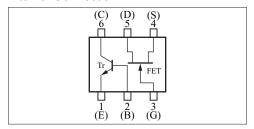
| Parameter | | Symbol | Rating | Unit | |
|----------------|---------------------------------------|------------------|-------------|------|--|
| Tr | Collector-base voltage (Emitter open) | V _{CBO} | 30 | V | |
| | Collector-emitter voltage (Base open) | V _{CEO} | 20 | V | |
| | Emitter-base voltage (Collector open) | V _{EBO} | 3 | V | |
| | Collector current | I_{C} | 50 | mA | |
| CCD | Limiting element voltage | V _{max} | 40 | V | |
| load device | Limiting element current | I _{max} | 10 | mA | |
| Overall | Total power dissipation * | P _T | 125 | mW | |
| | Junction temperature | T _j | 125 | °C | |
| | Storage temperature | T _{stg} | -55 to +125 | °C | |

Note) * : Measuring on substrate at 17 mm \times 10 mm \times 1 mm



Marking Symbol: 4V

Internal Connection



■ Electrical Characteristics $T_a = 25$ °C±3°C

• Tr

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|---------------------------------------|-------------------|--|-----|-----|------|------|
| Collector-base voltage (Emitter open) | V_{CBO} | $I_C = 100 \mu A, I_E = 0$ | 30 | | | V |
| Emitter-base voltage (Collector open) | V_{EBO} | $I_E = 10 \mu A, I_C = 0$ | 3 | | | V |
| Base-emitter voltage | V_{BE} | $V_{CE} = 10 \text{ V}, I_{C} = 2 \text{ mA}$ | | 720 | | mV |
| Forward current transfer ratio | h_{FE} | $V_{CE} = 10 \text{ V}, I_{C} = 2 \text{ mA}$ | 25 | | 250 | _ |
| Transition frequency * | f_T | $V_{CB} = 10 \text{ V}, I_E = -15 \text{ mA}, f = 200 \text{ MHz}$ | 800 | | 1200 | MHz |
| Power gain | G _P | $V_{CB} = 10 \text{ V}, I_E = -1 \text{ mA}, f = 100 \text{ MHz}$ | | 20 | | dB |

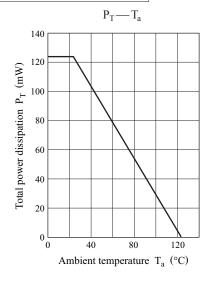
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

• CCD Load Device

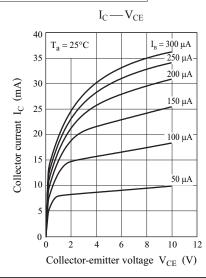
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--------------------|--------|----------------------------------|-----|------|-----|------|
| Pinchi off current | I_P | $V_{DS} = 10 \text{ V}, V_G = 0$ | 3.5 | | 5.5 | mA |
| Output impedance | Zo | $V_{DS} = 10 \text{ V}, V_G = 0$ | | 0.05 | | ΜΩ |

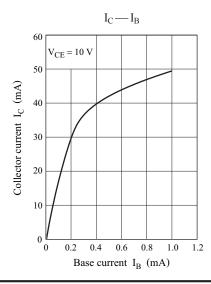
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

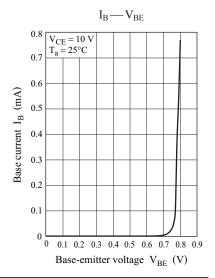
Common characteristics chart



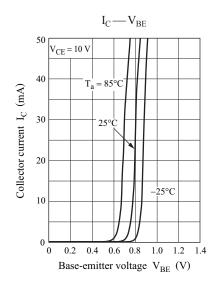
Characteristics charts of Tr

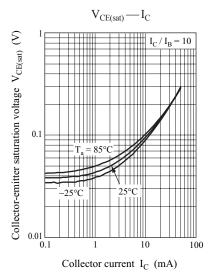


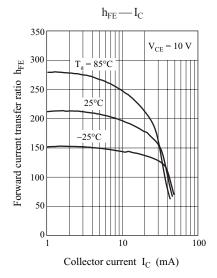


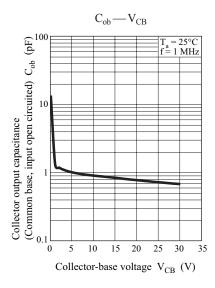


^{*:} Pulse measurement

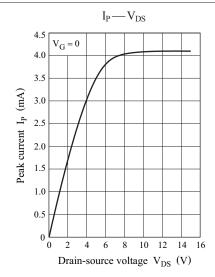








Characteristics charts of CCD load device



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